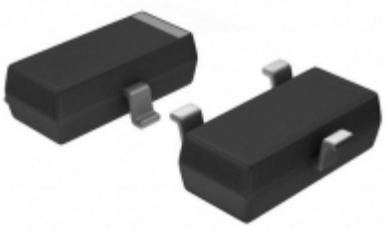


	<p>SI2343CDS-T1-GE3</p>
	<p>Hersteller-Teilenummer: SI2343CDS-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 30V 5.9A SOT-23</p> <p>Datenblätter:  SI2343CDS-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 150157 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI2343CDS-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 30V 5.9A SOT-23
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	150157 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	1.25W (Ta), 2.5W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	5.9A (Tc)
Rds On (Max) @ Id, Vgs	45 mOhm @ 4.2A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	21nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	590pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)



























SI2343CDS-T1-GE3 ist neu im Original, Suche SI2343CDS-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2343CDS-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI2343CDS-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI2343DS AOS SI2343DS AOS</p>	 <p>SI2343CDS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 5.9A SOT-23</p>	 <p>SI2343CDS VISHAY SI2343CDS VISHAY</p>	 <p>SI2342DS-T1-GE3 Vishay / Spectrol MOSFET N-CH 8V 6A SOT-23</p>
 <p>SI2343DS-T1 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 3.1A SOT23</p>	 <p>SI2343ADS-T1-GE3 V SI2343ADS-T1-GE3 V</p>	 <p>SI2343DS-T1-E3 Vishay / Siliconix MOSFET P-CH 30V 3.1A SOT23-3</p>	 <p>SI2343DS-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 3.1A SOT23-3</p>

heiße Teile

Mehr

 SI2335DS-T1-GE3	 SI2335DS-T1-GE3	 SI2336DS-T1-E3	 SI2336DS-T1-GE3	 SI2336DS-T1-GE3
 SI2337DS	 SI2337DS-T1-E3	 SI2337DS-T1-E3	 SI2337DS-T1-GE3	 SI2337DS-T1-GE3
 SI2338DS-T1-E3	 SI2338DS-T1-GE3	 SI2338DS-T1-GE3	 SI2341DS	 SI2341DS-T1-E3
 SI2341DS-T1-E3	 SI2341DS-T1-GE3	 SI2341DS-T1-GE3	 SI2342DS-T1-E3	 SI2342DS-T1-GE3
 SI2342DS-T1-GE3	 SI2343ADS-T1-GE3	 SI2343CDS	 SI2343CDS-T1-E3	 SI2343CDS-T1-GE3
 SI2343DS-T1-E3	 SI2343DS-T1-E3	 SI2343DS-T1-GE3	 SI2343DS-T1-GE3	 SI2344DS-E3
 SI2347DS-T1-GE3	 SI2347DS-T1-GE3	 SI2351DS-T1-E3	 SI2351DS-T1-E3	 SI2351DS-T1-GE3
 SI2351DS-T1-GE3	 SI2356DS-T1-GE3	 SI2356DS-T1-GE3	 SI2365EDS	 SI2365EDS-T1-GE3
 SI2365EDS-T1-GE3	 SI2366DS-T1-E3	 SI2366DS-T1-GE	 SI2366DS-T1-GE3	 SI2366DS-T1-GE3
 SI2367DS-T1-E3	 SI2367DS-T1-GE3	 SI2367DS-T1-GE3	 SI2369DS-T1-GE3	 SI2369DS-T1-GE3

Contact us: Info@Y-IC.com

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